

KSC1393

TV VHF Tuner RF Amplifier (Forward AGC)

- High Current Gain Bandwidth Product : f_T=700MHz (TYP.)
- Low Noise Figure : NF=3.0dB (MAX.) at f=200MHz
- Low Reverse Transfer Capacitance : C_{RE}=0.5pF (MAX.)



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

| Symbol | Parameter | Ratings | Units |
|------------------|-----------------------------|-----------|-------|
| V _{CBO} | Collector-Base Voltage | 30 | V |
| V _{CEO} | Collector-Emitter Voltage | 30 | V |
| V _{EBO} | Emitter-Base Voltage | 4 | V |
| I _C | Collector Current | 20 | mA |
| P _C | Collector Power Dissipation | 250 | mW |
| T _J | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C |

Electrical Characteristics T_a=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|-------------------|-------------------------------------|--|------|------|------|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | $I_{C}=10\mu A, I_{E}=0$ | 30 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I _C =5mA, I _B =0 | 30 | | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | I _E =10μA, I _C =0 | 4 | | | V |
| I _{CBO} | Collector Cut-off Current | V _{CB} =20V, I _E =0 | | | 0.1 | μΑ |
| h _{FE} | DC Current Gain | V _{CE} =10V, I _C =2mA | 40 | | 180 | |
| f _T | Current Gain Bandwidth Product | V _{CE} =10V, I _C =3mA | 400 | 700 | | MHz |
| C _{RE} | Reverse Transfer Capacitance | V _{CB} =10V, I _E =0, f=1MHz | | 0.35 | 0.5 | pF |
| G _{PE} | Power Gain | V _{CE} =10V, I _C =3mA f=200MHz | 20 | 24 | | dB |
| I _{AGC} | AGC Current | I _E at G _R = -30dB, f=200MHz | | -10 | -12 | mA |
| NF | Noise Figure | V _{CE} =10V, I _C = 3mA f=200MHz | | 2.0 | 3.0 | dB |

h_{FE} Classification

| Classification | R | 0 | Y |
|-----------------|---------|----------|----------|
| h _{FE} | 40 ~ 80 | 60 ~ 140 | 90 ~ 180 |

Typical Characteristics

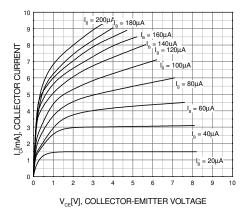


Figure 1. Static Characteristic

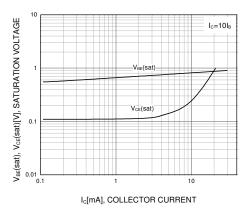


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

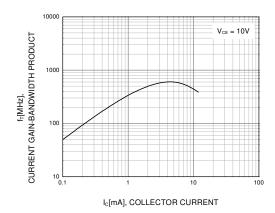


Figure 5. Current Gain Bandwidth Product

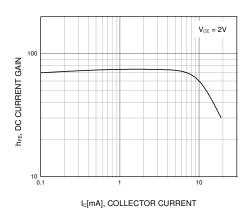


Figure 2. DC current Gain

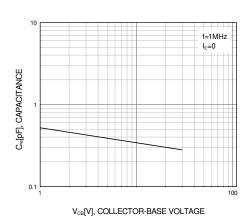
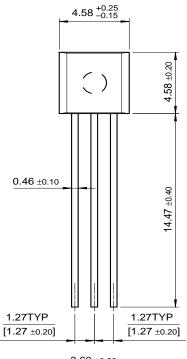


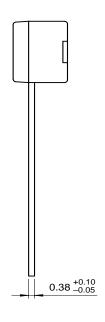
Figure 4. Reverse Capacitance

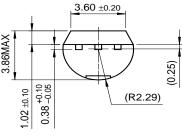


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Rev. I1

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|--------------------------|---------------------------|---|
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